Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK1061

High Speed Switching Applications Analog Switch Applications Interface Applications

- Excellent switching times: $t_{on} = 14 \text{ ns (typ.)}$
- High forward transfer admittance: $|Y_{fs}| = 100 \text{ mS (min)}$
- Low on resistance: RDS (ON) = 0.6Ω (typ.)
- Enhancement-mode
- Complementary to 2SJ167

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DS}	60	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	200	mA	
	Pulse	I _{DP}	800		
Drain power dissipation (Ta = 25°C)		P _D	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

4.2MAX. 0.55MAX. 1.27 1 2 3 660 25° 1. SOURCE 2. DRAIN 3. GATE

JEDEC

JEITA

TOSHIBA

2-4E1E

Weight: 0.13 g (typ.)

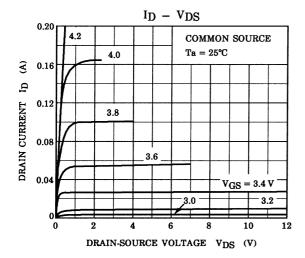


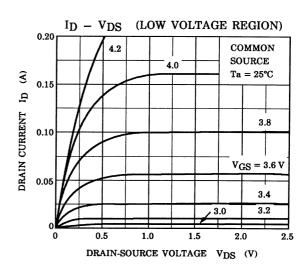
Electrical Characteristics (Ta = 25°C)

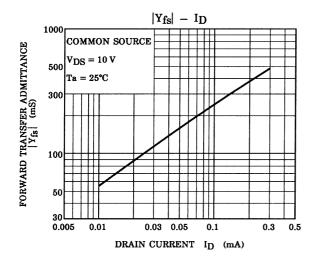
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0	_	_	10	μΑ
Drain-source breakdown voltage		V (BR) DSS	I _D = 1 mA, V _{GS} = 0	60	_	_	V
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	2	_	3.5	V
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 50 mA	100	_	_	mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$		0.6	1.0	Ω
Drain-source ON voltage		V _{DS (ON)}	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$		30	50	mV
Input capacitance		C _{iss}			55	65	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz		13	18	pF
Output capacitance		C _{oss}			40	50	pF
Switching time	Rise time	t _r	$I_{D} = 100 \text{mA}$	_	8	_	
	Turn-on time	t _{on}	VIN VOUT VDD = 30 V		14	_	- ns
	Fall time	t _f	# # 9 30 V		35		
	Turn-off Time	t _{off}	$\begin{array}{l} \text{D.U.} \leq 1\% \\ \text{V}_{\text{IN}} \colon t_r, t_f < 5 \text{ ns} \\ (Z_{\text{out}} = 50 \; \Omega) \end{array}$	_	75		

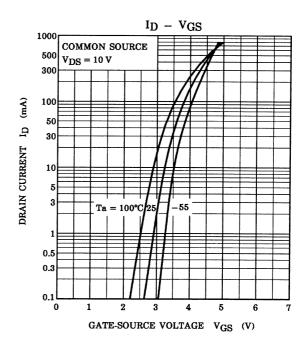
Note: This transistor is the electrostatic sensitive device. Please handle with caution.

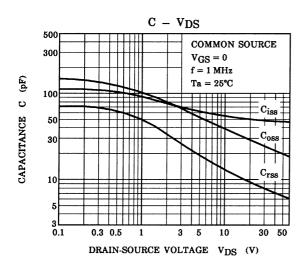
2 2003-03-25



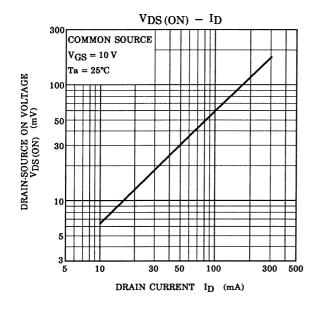


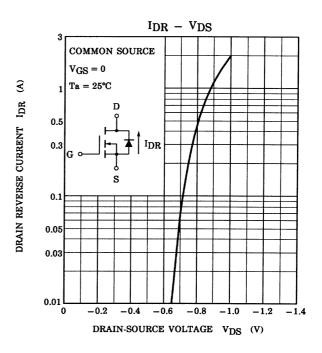


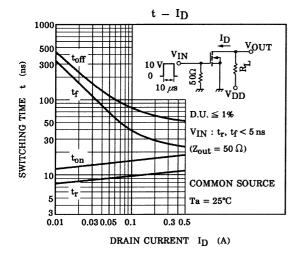


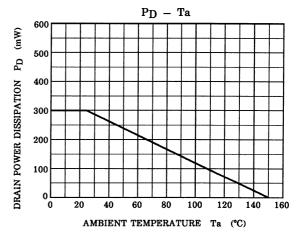


3 2003-03-25









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5

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